A Correction has been published on 15th June 2020 relating to Fig. S3 of this Supplementary Information document. Please see the accompanying Correction for further details (DOI: 10.1039/D0TA90124E).

Supporting Information for

Triple Cation Additive $NH_3^+C_2H_4NH_2^+C_2H_4NH_3^+$ induced Phase-stable Inorganic α -CsPbI₃ Perovskite Films for Use in Solar Cells

Xihong Ding¹, Haibin Chen¹, Yahan Wu¹, Shuang Ma¹, Songyuan Dai^{1,2*}, Shangfeng Yang³, Jun Zhu^{4*}

¹Beijing Key Laboratory of Novel Thin-Film Solar Cells, Beijing Key Laboratory of Energy Safety and Clean Utilization, North China Electric Power University, Beijing 102206, China

²Key Laboratory of Photovoltaic and Energy Conservation Materials, Hefei Institutes of Physical Science, Chinese Academy of Sciences, Hefei 230031, China

³Department of Materials Science and Engineering, University of Science and Technology of China Hefei 230026, China

⁴National Engineering Lab of Special Display Technology, State Key Lab of Advanced Display Technology, Academy of Opto-Electronic Technology, Hefei University of Technology, Hefei, 230009, China *Corresponding authors:

Emails: sydai@ncepu.edu.cn; jzhu@hfut.edu.cn

Experimental details

Materials: DETAI₃ was synthesized by reacting DETA (98%+, ACROS OGANICS) and hydroiodic acid (>45%, Sinopharm Chemical Reagent Co. Ltd) with a molar ratio of 1:3.5 in an ice bath for 2 h with stirring. The excess hydroiodic acid was used to ensure all the DETA turn into DETAI₃. The precipitate was collected by rotary evaporation at 60 °C, washed three times with copious diethyl ether until the supernatant turned to colorless, and then vacuum-dried at 50 °C for 1 h. EDAI₂ and PZI₂ were synthesized following similar procedure. The HPbI₃ was synthesized as previously reported.¹ The CsPbI₃·xDETAI₃ precursor solution was prepared by dissolving 0.5 mmol HPbI₃ and 0.5 mmol of CsI (99%, TCI) in 1 ml of DMF to form a 0.5 M precursor solution mixed with different x ratios of 0.5 M DETAI₃ solution. Then the CsPbI₃·xDETAI₃ precursor solution was filtered with a PTFE filter with 0.45 µm pore. The hole transporting material (HTM) was prepared as previous work.² In brief, 15 mg P3HT (poly(3-hexylthiophene-2,5-diyl), Rieke Metals, RMI-001EE, J&K chemical Ltd.) was dissolved in 1 mL chlorobenzene with 54 µL Li-TFSI stock solution (10 mg mL⁻¹ in acetonitrile) and 10.2 µL TBP. All the other chemicals were purchased from Sigma Aldrich and used as received without further purification. Patterned FTO glass (15 ohm sq⁻¹, Pilkington TEC) were cleaned sequentially by ultrasonication in mild detergent,

deionized water, acetone and ethanolamine. The substrates were exposed to UV-ozone for 15 min prior to the spin coating step.

Solar cell fabrication: A dense TiO₂ compact layer (compact-TiO₂) was deposited on the cleaned FTO by spray pyrolysis with an airbrush, using N₂ as carrier gas, at 430 °C for 1 h from a precursor solution of 0.6 ml of titanium diisopropoxide and 0.4 ml of bis (acetylacetonate) in 7 ml of anhydrous isopropanol. The CsPbI₃·*x*DETAI₃ precursor solutions were then spin-coated onto the prewarmed bl-TiO₂-coated substrate at 3500 rpm for 30 s, followed by annealing at 150 °C for 40 min. After the films were cooled down to room temperature, a layer of HTM was spin-coated at 4600 rpm for 20 s. Finally, a 60-nm-thick Au contact layer was thermally evaporated as back contact. All of the processes were performed in air ambient at a relative humidity <25%.

Characterization: Devices were tested in air ambient. The solar simulators are Newport Oriel Sol3A solar simulators with Xenon lamps. A calibrated Si reference solar cell was used to set the intensity of the lamp to 100 mW cm⁻² AM 1.5 conditions. Current density–voltage (J-V) scans were taken from forward bias to reverse bias with a scan rate of 200 mV s⁻¹ (scan parameters: step size = 20 mV, delay time =10 ms). Devices were illuminated for 5 s prior to starting the J-V sweep. To minimize possible J_{SC} overestimation from current collecting outside the device area, a mask was used, and the equivalent current densities were achieved for the solar

cell. Stabilized power output was measured by holding the device at a constant voltage corresponding to the voltage at the maximum power point of the J-V scan. IPCE spectra were recorded under illumination of monochromatic light from the halogen tungsten lamp using a monochromator (Enlitech, Taiwan) and detected by a computer-controlled lock-in amplifier. XRD patterns were collected by a Rigaku diffractometer (RINT-TTR III) with Cu K_{α} radiation (k = 1.54056). UV–Vis absorption spectra were recorded by an ultraviolet-visible-near-infrared spectrometer (SolidSpec-3700/3700DUV, Shimadzu). XPS measurement was taken on a Thermo Scientific K-Alpha XPS instrument with Al K_{α} radiation (hv = 1486.68 eV). SEM images were collected using a Zeiss SEM (EVO18). Raman spectroscopy was performed by Renishaw inVia Reflex with a laser of 785 nm. Fourier transform infrared spectroscopy (FT-IR, ThermoFisher IS50R, USA) was used to collect the spectral data for various solution in the range of 4000-500 cm⁻¹. PL spectra were performed using a standard 450 W Xenon CW lamp, and the TRPL were recorded on a pulsed nitrogen/dye laser (QM400, Photo Technology International, USA.). The contact angle measurement was performed using OCA15EC with water.



Figure S1. A typical forward and reverse scan *J*-*V* curve of the perovskite solar cells based on CsPbI₃ 0.05DETAI₃ samples.



Figure. S2 Operational stability of un-encapsulated CsPbI₃·*x*DETAI₃ (*x*=0, 0.05) PSC at bias voltage of 0.54 V and 0.83 V, respectively, for 120 min. (examined at a maximum-power-point under continuous full-sun illumination at ~30°C, 60-70% RH in ambient air)



Figure S3. a) XRD patterns of CsPbI₃ \cdot 0.05EDAI₂ films of day 1 and day 60 stored in a dark dry box, inset image is the structure of ethylenediamine. b) XRD patterns of CsPbI₃ \cdot 0.05PZI₂ films of day 1 and day 60 stored in a dark dry box, inset image is the structure of pyrazine.



Figure S4. Photographs of CsPbI₃·*x*DETAI₃ (x=0, 0.05) in humid environment (~30°C, 60-70% RH)

Note 1

"A dark dry box" we noted in this paper was referred to a dark dry box

with 15-20% RH and a temperature of 25-30 °C.

Reference

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